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PATENT
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant	Bernd Schoettker, et al.
Serial No. 09/624,252	Filing Date: July 24, 2000
Title of Application:	Method For Growing Nitrogenous Semiconductor Crystal Materials

Assistant Commissioner for Patents
Washington, DC 20231

Revocation and New Power Of Attorney

Dear Sir:

Applicants, AIXTRON AG, a company of GERMANY, having its principal place of business at Kackertstrasse 15-17; D-52072 Aachen, Germany hereby revoke all previous powers of attorney and appoints the following attorney to prosecute this patent and transact all business in the United States Patent and Trademark Office connected therewith, receive all communications from the United States Patent and Trademark Office, to receive the Letters Patent, and be its agent for service of process in connection herewith:

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To the best of my knowledge, AIXTRON AG is the assignee of record of the patent application identified above (assignment recorded 2/14/01 under Reel/Frame 011526/0695).

AIXTRON AG

Aachen, 04/12-2002
Date

By 
Mr. Holger Jurgensen
Its President

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